

Type	Hits	Search Text	DBS	Time Stamp	Comments	Error Definition
IS&R	1	("6180439").PN.	USPAT	2004/03/19 10:34		
IS&R	4	(("3890632") OR ("4330363") OR ("4466073") OR ("550070")) .PN.	USPAT	2001/04/03 10:08		
BRS	1322	438/149,162,164,166,47 9,482,486,487.cc1s.	USPAT	2001/04/03 10:09		
BRS	242	438/149,162,164,166,47 9,482,486,487.cc1s. and (taper\$3 or slant\$3 or trapezoid\$2 or angl\$3)	USPAT	2001/04/03 10:11		
BRS	32	438/164.cc1s. and (taper\$3 or slant\$3 or trapezoid\$2 or angl\$3)	USPAT	2001/04/03 10:12		
BRS	1	((silicon adj oxide) and (silicon adj oxynitride) .TI.	USPAT	2003/01/15 14:58		
BRS	63	((silicon adj oxide) and (silicon adj oxynitride) with (gate adj insulating)	USPAT	2004/09/07 14:47		
BRS	116	(silicon adj oxynitride) with TEOS	USPAT	2003/01/15 16:41		

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9 BRS	13	(silicon adj oxynitride) with (TEOS and nitrogen)	USPAT	2003/01/15 16:45		
10 BRS	14	(silicon adj oxynitride) and (TEOS with (nitrogen same oxide))	USPAT	2004/09/07 14:53		
11 IS&R	5	(("6465287") OR ("6482686") OR ("6495404") OR ("6528358") OR ("5970327")) . PN.	USPAT	2004/03/02 13:53		
12 BRS	799	Plasma with treatment with semiconductor	USPAT	2004/03/04 14:09		
13 BRS	86	(Plasma with treatment with semiconductor) and (semiconductor with organic)	USPAT	2004/03/04 15:01		
14 IS&R	1	("5728259") . PN.	USPAT	2004/03/04 15:37		
15 BRS	726	134/1.2,1.3.cc1s.	USPAT	2004/03/04 15:37		
16 BRS	16	134/1.2,1.3.cc1s. and semiconductor and TFT	USPAT	2004/03/04 17:10		
17 BRS	2	organic adj diffusion adj barrier	USPAT	2004/03/04 17:10		

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18 BRS	146	organic with (diffusion adj barrier)	USPAT	2004/03/04 17:32		
19 BRS	98	(organic with (diffusion adj barrier)) and semiconductor	USPAT	2004/03/04 17:11		
20 BRS	108	resin with (diffusion adj barrier)	USPAT	2004/03/04 17:30		
21 BRS	5	(resin with (diffusion adj barrier)) and semiconductor	USPAT	2004/03/04 17:30		
22 BRS	394	organic same (diffusion adj barrier)	USPAT	2004/03/04 17:33		
23 BRS	278	(organic same (diffusion adj barrier)) and semiconductor	USPAT	2004/03/04 17:32		
24 BRS	2379	organic with diffusion	USPAT	2004/03/04 17:34		
25 BRS	14	organic adj diffusion	USPAT	2004/03/04 17:36		
26 BRS	181	resin with (environment\$2 adj protection)	USPAT	2004/03/04 17:36		

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27	BRS 30	(resin with (environment\$2 adj protection)) and semiconductor	USPAT	2004/03/0 4 17:36		
28	IS& R 4	(("6531862") OR ("5575883") OR ("5902993") OR ("6006763")) . PN .	USPAT	2004/03/1 9 10:35		
29	IS& R 4	(("5531862") OR ("5575883") OR ("5902993") OR ("6006763")) . PN .	USPAT	2004/03/1 9 10:36		
30	IS& R 1	("5728259") . PN .	USPAT	2004/09/0 7 14:47		
31	IS& R 2	(("5147826") OR ("4330363")) . PN .	USPAT	2004/09/0 7 15:06		
32	BRS 221	(amorphous adj silicon) and crystallization and (metal with catalyst)	USPAT	2004/09/0 7 15:08		
33	BRS 43	((amorphous adj silicon) and crystallization and (metal with catalyst) and gettering	USPAT	2004/09/0 7 15:18		
34	BRS 190	gettering with halogen	USPAT	2004/09/0 7 15:19		

Type	Hits	Search Text	DBs	Time stamp	Comment s	Error Definition
35 BRS	167	(gettering with halogen) and silicon	USPAT	2004/09/07 16:21		
36 IS&R	1	("6180439") . PN .	USPAT	2004/09/07 15:39		
37 BRS	78	(heavy adj metal) and getter\$3 and halogen	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 16:57		
38 BRS	86	gas with phase with getter\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 16:43		
39 BRS	12	(gas with phase with getter\$3) and halogen	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 16:34		
40 BRS	3	("5322590" "5658418" "5683538") . PN .	USPAT	2004/09/07 16:37		

Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
41	BRS 13	("4417822" "4500563" "4647774" "4919542" "4979134" "4956538" "4984902" "5098197" "5154512" "5226732" "5156461" "5326171" "5387777") .PN .	USPAT	2004/09/07 16:37		
42	BRS 13	("4417822" "4500563" "4647774" "4919542" "4979134" "4956538" "4984902" "5098197" "5154512" "5226732" "5156461" "5326171" "5387777") .PN .	USPAT	2004/09/07 16:37		
43	BRS 1	"4816113" .PN .	USPAT	2004/09/07 16:37		
44	BRS 46	(semiconductor with cleaning with halogen) and oxidation	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 17:00		

Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
45	BRS 46	((semiconductor with cleaning with halogen) and oxidation) and (impurities or metal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/08 10:36		
46	BRS 3260	film with irradiation with (UV or infrared)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/07 18:01		
47	BRS 15	(semiconductor adj film) with irradiation with (UV or infrared)	USPAT	2004/09/07 18:03		
48	BRS 27	(semiconductor adj film) with irradiation with (UV or infrared)	USPAT; EPO; JPO; DERWENT; IBM TDB	2004/09/07 18:06		
49	BRS 201	semiconductor with (UV or infrared)	USPAT	2004/09/07 18:07		
50	IS&R 1	("5704986") . PN.	USPAT	2004/09/08 12:57		
51	BRS 277	crystallization with infrared	USPAT	2004/09/08 12:58		
52	BRS 93	(crystallization with infrared) and (amorphous adj silicon)	USPAT	2004/09/09 09:41		

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53 IS&R	1	("6180439") . PN.	USPAT	2004/09/09 09:41		